





SBVS457A - AUGUST 2024 - REVISED SEPTEMBER 2024

TPS7A20U

TPS7A20U 75mA, Low-Noise, Low-IQ, High-PSRR LDO

1 Features

Low output voltage noise: 7µV_{RMS}

No noise-bypass capacitor required

High PSRR: 89dB at 1kHz

Very low I_Q: 6.5µA

Input voltage range: 1.6V to 6.0V

Output voltage range: 0.8V to 5.5V

Output voltage tolerance: ±1.5% (max)

Very low dropout:

- 95mV (max) at 75mA (V_{OUT} = 1.5V to 5.5V)

Low inrush current

Smart enable pulldown

Stable with 1µF minimum ceramic output capacitor

0.616mm × 0.616mm DSBGA package

2 Applications

- Smartphones and tablets
- IP network cameras
- Portable medical equipment
- Smart meters and field transmitters
- Motor drives
- Wearables

3 Description

The TPS7A20U is an ultra-small, low-dropout (LDO) linear regulator that sources 75mA of output current. The TPS7A20U is designed to provide low noise, high PSRR, and excellent load and line transient performance. This performance meets the requirements of RF and other sensitive analog circuits. Using innovative design techniques, the TPS7A20U offers ultra-low noise performance without the addition of a noise bypass capacitor. The TPS7A20U also provides the advantage of low quiescent current, which is designed for batterypowered applications. With a 1.6V to 6.0V input voltage range and a 0.8V to 5.5V output range, the TPS7A20U is applicable for a wide variety of applications. The device uses a precision reference circuit to provide a maximum accuracy of 1.5% over load, line, and temperature variations.

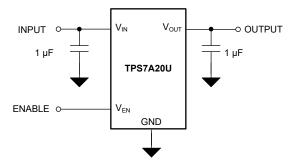
The TPS7A20U features an internal soft-start to lower the inrush current, thus minimizing the input voltage drop during start-up. The device is stable with small ceramic capacitors, allowing for a small overall solution size.

The TPS7A20U has a smart enable input circuit with an internally controlled pulldown resistor that keeps the LDO disabled. The LDO remains disabled even when the EN pin is left floating and helps eliminate the external components used to pulldown the EN pin.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)			
TPS7A20U	YCK (DSBGA, 4)	0.616mm × 0.616mm			

- For more information, see the Mechanical, Packaging, and Orderable Information
- The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Application Schematic



Table of Contents

1 Features1	6.4 Device Functional Modes17
2 Applications1	7 Application and Implementation18
3 Description1	7.1 Application Information
4 Pin Configuration and Functions3	
5 Specifications4	7.3 Power Supply Recommendations22
5.1 Absolute Maximum Ratings4	
5.2 ESD Ratings4	
5.3 Recommended Operating Conditions4	8.1 Device Support24
5.4 Thermal Information5	8.2 Receiving Notification of Documentation Updates24
5.5 Electrical Characteristics	8.3 Support Resources24
5.6 Switching Characteristics	
5.7 Typical Characteristics	8.5 Electrostatic Discharge Caution24
6 Detailed Description14	
6.1 Overview14	
6.2 Functional Block Diagram14	
6.3 Feature Description15	



4 Pin Configuration and Functions

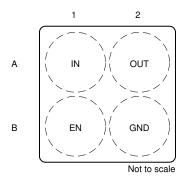


Figure 4-1. YCK Package, 4-Pin DSBGA (Top View)

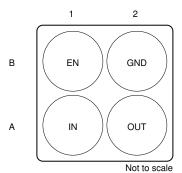


Figure 4-2. YCK Package, 4-Pin DSBGA (Bottom View)

Pin Functions

P	PIN		DESCRIPTION
NO.	NAME	I/O	DESCRIPTION
A1	IN	I	Input voltage supply. For best transient response and to minimize input impedance, use the nominal value or larger capacitor from IN to ground. See the <i>Recommended Operating Conditions</i> table. Place the input capacitor as close to the IN and GND pins of the device as possible.
A2	OUT	0	Regulated output voltage. A low equivalent series resistance (ESR) capacitor is required from OUT to ground for stability. For best transient response, use the nominal recommended value or larger capacitor, as listed in the <i>Recommended Operating Conditions</i> table. Place the output capacitor as close to the OUT and GND pins of the device as possible. An internal 150Ω (typical) pulldown resistor prevents a charge from remaining on V_{OUT} when the regulator is in shutdown mode ($V_{EN} < V_{EN(LOW)}$).
B1	EN	I	Enable input. A low voltage ($<$ V _{EN(LOW)}) on this input turns the regulator off and discharges the output pin to GND. A high voltage ($>$ V _{EN(HI)}) on this pin enables the regulator output. This pin has an internal 500k Ω pulldown resistor to hold the regulator off by default. When V _{EN} $>$ V _{EN(HI)} , the 500k Ω pulldown is disconnected to reduce input current.
B2	GND	_	Common ground.

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (3)

		MIN	MAX	UNIT
	V _{IN}	-0.3	6.5	
Voltage	Vout	-0.3	6.5 or V _{IN} + 0.3 ⁽²⁾	V
	V _{EN}	-0.3	6.5	
Current	Maximum output ⁽⁴⁾	Internally limited		Α
Tomporatura	Operating junction, T _J	-40	150	°C
Temperature	Storage, T _{stg}	-65	150	C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- The maximum value of V_{OLIT} is the lesser of 6.5V or $(V_{IN}+0.3V)$.
- (3) All voltages are with respect to the GND pin.
- (4) Internal thermal shutdown circuitry protects the device from permanent damage.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electro	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±750	V

- (1) JEDEC document JEP155 states that 500V HBM allows safemanufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safemanufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	NOM	MAX	UNIT
V _{IN}	Input supply voltage	1.6		6.0	V
V _{EN}	Enable input voltage	0		6.0	V
V _{OUT}	Nominal output voltage range	0.8		5.5	V
I _{OUT}	Output current	0		75	mA
C _{IN}	Input capacitor ⁽²⁾		1		μF
C _{OUT}	Output capacitance ⁽³⁾	0.47		10	μF
ESR	Output capacitor effective series resistance			50	mΩ
T _J	Operating junction temperature	-40		125	°C

- (1) All voltages are with respect to GND.
- (2) An input capacitor is not required for LDO stability. However, an input capacitor with an effective value of 0.47µF minimum is recommended to counteract the effect of source resistance and inductance, which sometimes causes symptoms of system-level instability such as ringing or oscillation, especially in the presence of load transients.
- (3) To help achieve fast settling and avoid instability, make sure the output capacitance (including tolerance, bias voltage, temperature variations, and so forth) falls within the specified range.



5.4 Thermal Information

		TPS7A20U	
THERMAL METRIC ⁽¹⁾		YCK (DSBGA)	UNIT
		4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	201.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	2.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	69.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	1.4	°C/W
ΨЈВ	Junction-to-board characterization parameter	69.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application note.

5.5 Electrical Characteristics

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at operating temperature range ($T_J = -40^{\circ}\text{C}$ to +125°C), $V_{IN} = V_{OUT(NOM)} + 0.3V$ or 1.6V, whichever is greater, $V_{EN} = 1.0V$, $I_{OUT} = 1\text{mA}$, $C_{IN} = 1\mu\text{F}$, $C_{OUT} = 1\mu\text{F}$ (unless otherwise noted); all typical values are at $T_J = 25^{\circ}\text{C}$

PARAMETER		TEST COI	TEST CONDITIONS		TYP	MAX	UNIT	
A)/	0.44	$V_{IN} = (V_{OUT(NOM)} + 0.3V)$ to	V _{OUT} ≥ 1.85V	-1.5		1.5	%	
ΔV _{OUT}	Output voltage tolerance	6.0V, I _{OUT} = 1 mA to 75 mA	6.0V, I _{OUT} = 1 mA to 75 mA V _{OUT} < 1.85V			30	mV	
ΔV _{OUT}	Line regulation	$V_{IN} = (V_{OUT(NOM)} + 0.3V)$ to 6	V _{IN} = (V _{OUT(NOM)} + 0.3V) to 6.0V, I _{OUT} = 1mA		0.03		%/V	
ΔV _{OUT}	Load regulation	I _{OUT} = 1mA to 75mA			3		mV	
		., ., .,	T _J = 25°C		6.5	9.5		
Lean	Quiescent ground current	$V_{EN} = V_{IN} = 6V,$ $I_{OUT} = 0mA$	T _J = -40°C to 85°C			11		
I _{GND}	Quiescent ground current	1001 21111	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			15	μA	
		$V_{EN} = V_{IN} = 6 \text{ V}, I_{OUT} = 75 \text{m/s}$	A		1500			
		., ., ., ., .,	T _J = 25°C		0.07	0.2		
I _{SHDN}	Shutdown ground current	$V_{EN} = 0V$ (disabled), $V_{IN} = 6.0V$	T _J = -40°C to 85°C			2	μΑ	
		IIIV	T _J = -40°C to 125°C			10		
I _{GND(DO)}	I _{GND} in dropout	$V_{IN} \le V_{OUT(NOM)}$, $I_{OUT} = 0$ m.	A, V _{EN} = V _{IN}		6.5	15	μA	
V _{DO}	Dropout voltage	$I_{OUT} = 75\text{mA},$ $V_{OUT} = 95\% \times V_{OUT(NOM)}$	1.5V ≤ V _{OUT} ≤ 5.5V			95	mV	
1	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(NOM)},$ $V_{IN} = V_{OUT(NOM)} + 0.5V$	V _{OUT} < 1.5V	95	180	265	mA	
I _{CL}		$V_{OUT} = 0.9 \times V_{OUT(NOM)},$ $V_{IN} = V_{OUT(NOM)} + 0.3 \text{ V}$	V _{OUT} ≥ 1.5V	95	185	265		
			f = 100Hz		88			
				f = 1kHz		87		
		$I_{OUT} = 20\text{mA},$ $V_{IN} = V_{OUT} + 1.0V$	f = 10kHz		72		dB	
			f = 100kHz		62			
PSRR			f = 1MHz		42			
PORK	Power-supply rejection ratio		f = 100Hz		80		uБ	
			f = 1kHz		89			
		$I_{OUT} = 75\text{mA},$ $V_{IN} = V_{OUT} + 1.0V$	f = 10kHz		73			
		11N 1001	f = 100kHz		63			
			f = 1MHz		44			
M	Output naise valtage	BW = 10Hz to 100kHz,	I _{OUT} = 75mA		7		/	
V _N	Output noise voltage	V _{OUT} = 2.8V	I _{OUT} = 1mA		8		μV_{RMS}	
R _{PULLDOWN}	Output automatic discharge pulldown resistance	V _{EN} < V _{EN(LOW)} (output disab	oled), V _{IN} = 3.1V		285		Ω	
т	Thormal abutdown	T _J rising			165		°C	
T_{SD}	Thermal shutdown	T _J falling			140			



5.5 Electrical Characteristics (continued)

at operating temperature range ($T_J = -40^{\circ}C$ to +125°C), $V_{IN} = V_{OUT(NOM)} + 0.3V$ or 1.6V, whichever is greater, $V_{EN} = 1.0V$, $I_{OUT} = 1mA$, $C_{IN} = 1\mu F$, $C_{OUT} = 1\mu F$ (unless otherwise noted); all typical values are at $T_J = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{EN(LOW)}	Low input threshold	V _{IN} = 1.6V to 6.0V, V _{EN} falling until the output is disabled			0.3	V
V _{EN(HI)}	High input threshold	V _{IN} = 1.6V to 6.0V V _{EN} rising until the output is enabled	0.9			V
Vuvu o UVLO threshold	V _{IN} rising	1.11	1.35	1.59	V	
V _{UVLO}	OVEO tillestiold	V _{IN} falling	1.05	1.3	1.55	V
V _{UVLO(HYST)}	UVLO hysteresis			47		mV
I _{EN}	EN input leakage current	V _{EN} = 6.0V and V _{IN} = 6.0V		90	250	nA
R _{EN(PULL} -	Smart enable pulldown resistor	V _{EN} = 0.25V		500		ΚΩ

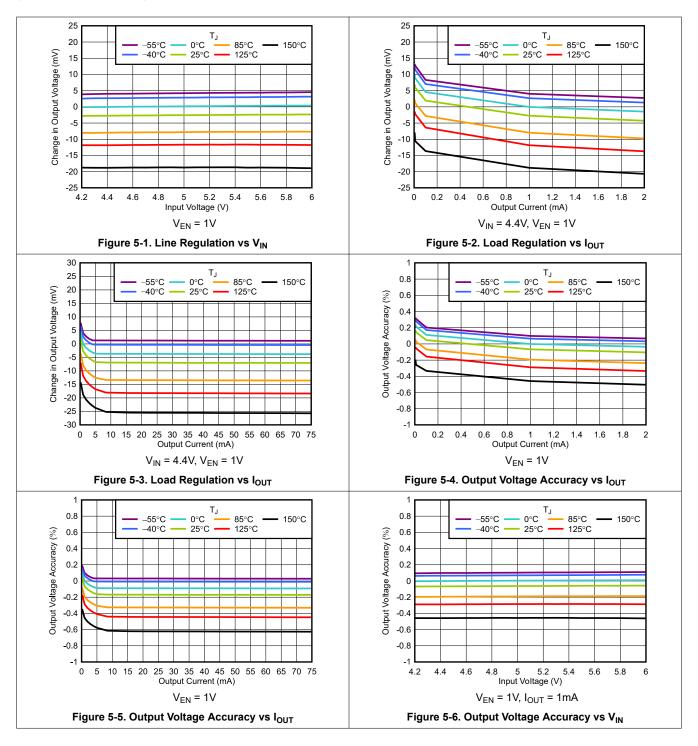
5.6 Switching Characteristics

at operating temperature range (T $_J$ = -40° C to +125 $^{\circ}$ C), V $_{IN}$ = V $_{OUT(NOM)}$ + 0.3V or 1.6V, whichever is greater, V $_{EN}$ = 1.0V, I $_{OUT}$ = 1mA, C $_{IN}$ = 1 $_{IN}$ F, C $_{OUT}$ = 1 $_{IN}$ F, C $_{OUT}$ ESL = 300pH, C $_{OUT}$ ESR = 8m $_{OUT}$ 0, board ESL = 1.5nH, board ESR = 5m $_{OUT}$ 0 (unless otherwise noted); all typical values are at T $_{J}$ = 25 $^{\circ}$ C

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{STR}	Start-up time	From $V_{EN} > V_{EN(HI)}$ to $V_{OUT} = 95\%$ of $V_{OUT(NOM)}$		750	1150	μs

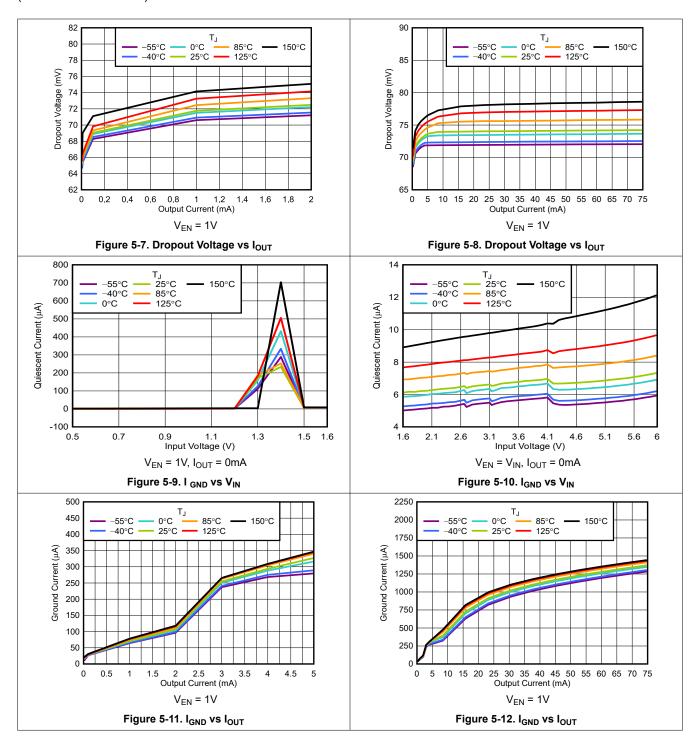
5.7 Typical Characteristics

 V_{IN} = $V_{OUT(NOM)}$ + 0.3V or 1.6V (whichever is greater), V_{OUT} = 4.1V, I_{OUT} = 1mA, C_{IN} = 1µF, C_{OUT} = 1µF, and T_A = 25°C (unless otherwise noted)





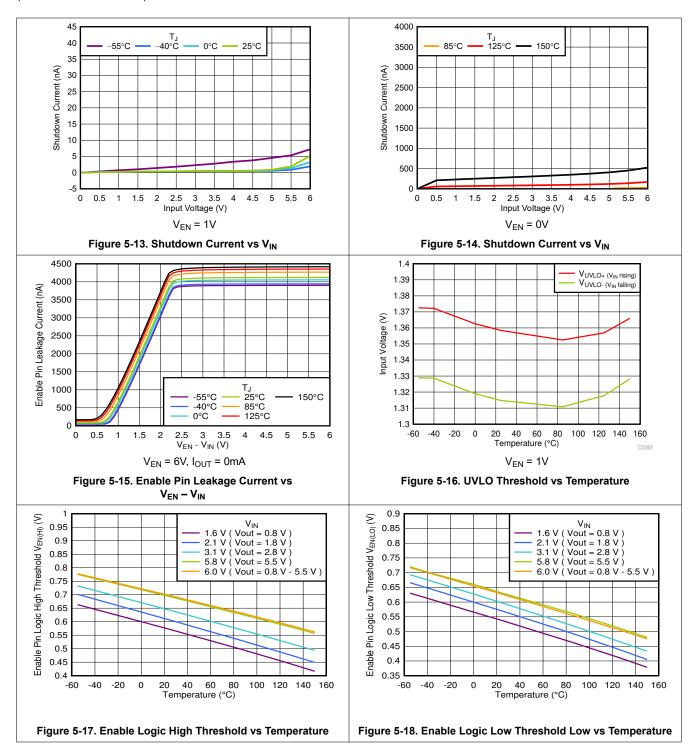
 V_{IN} = $V_{OUT(NOM)}$ + 0.3V or 1.6V (whichever is greater), V_{OUT} = 4.1V, I_{OUT} = 1mA, C_{IN} = 1µF, C_{OUT} = 1µF, and T_A = 25°C (unless otherwise noted)



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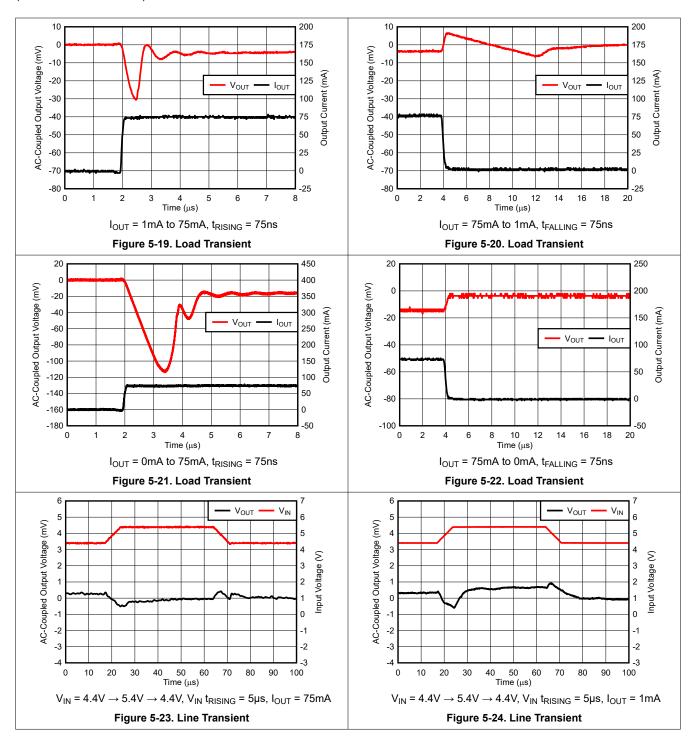
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 V_{IN} = $V_{OUT(NOM)}$ + 0.3V or 1.6V (whichever is greater), V_{OUT} = 4.1V, I_{OUT} = 1mA, C_{IN} = 1µF, C_{OUT} = 1µF, and T_A = 25°C (unless otherwise noted)





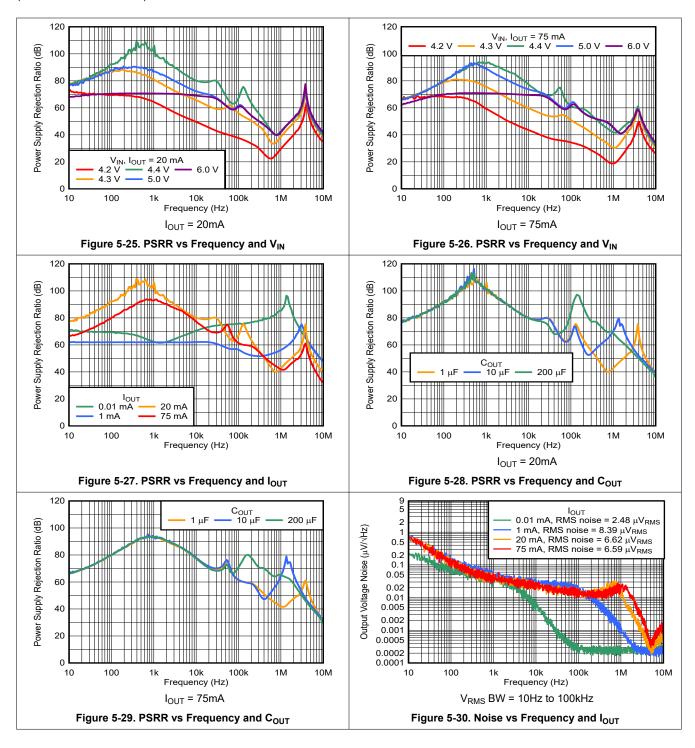
 $V_{IN} = V_{OUT(NOM)} + 0.3V$ or 1.6V (whichever is greater), $V_{OUT} = 4.1V$, $I_{OUT} = 1mA$, $C_{IN} = 1\mu F$, $C_{OUT} = 1\mu F$, and $T_A = 25^{\circ}C$ (unless otherwise noted)



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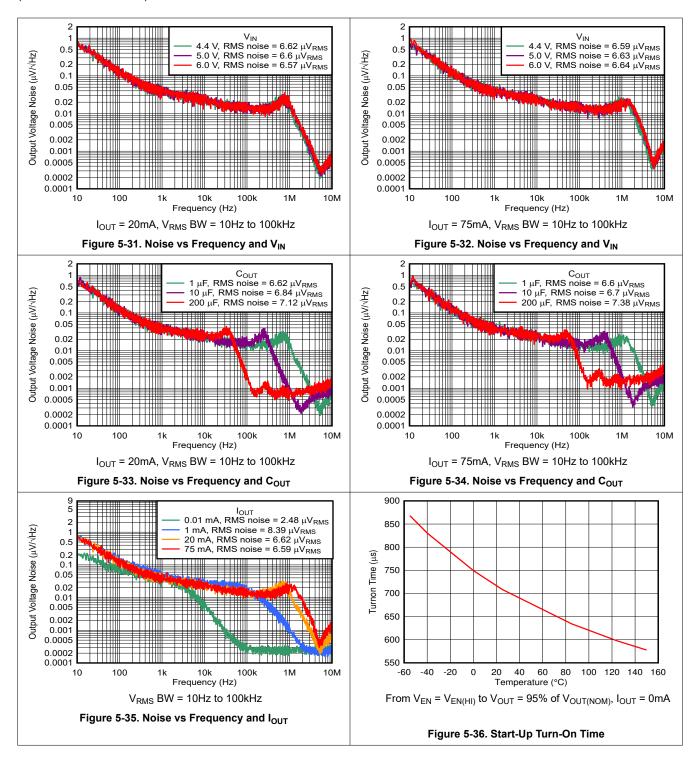
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 V_{IN} = $V_{OUT(NOM)}$ + 0.3V or 1.6V (whichever is greater), V_{OUT} = 4.1V, I_{OUT} = 1mA, C_{IN} = 1µF, C_{OUT} = 1µF, and T_A = 25°C (unless otherwise noted)





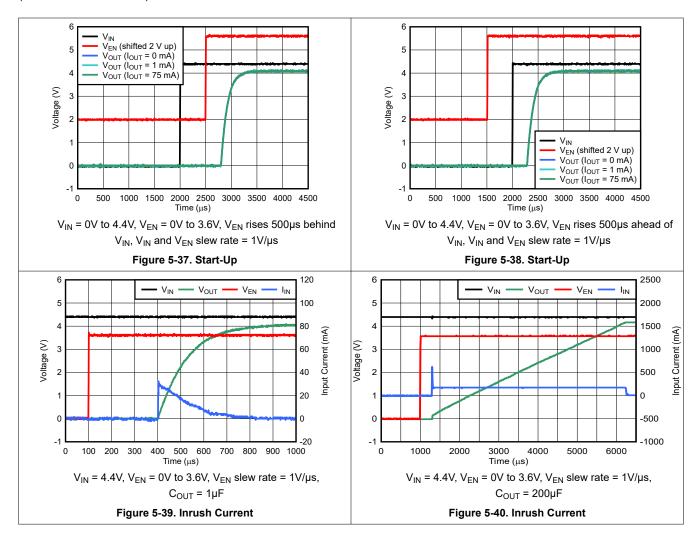
 V_{IN} = $V_{OUT(NOM)}$ + 0.3V or 1.6V (whichever is greater), V_{OUT} = 4.1V, I_{OUT} = 1mA, C_{IN} = 1µF, C_{OUT} = 1µF, and T_A = 25°C (unless otherwise noted)



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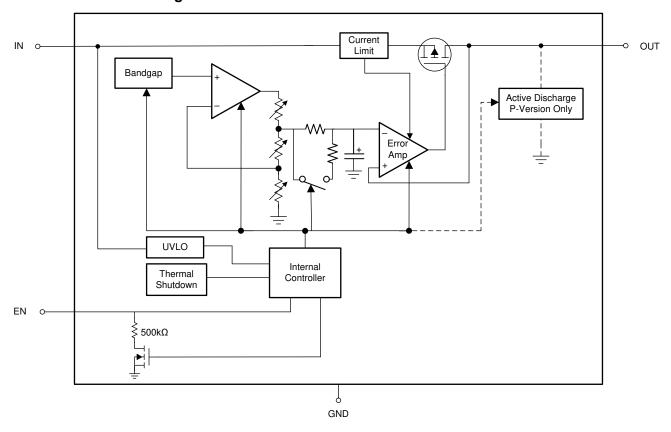
6 Detailed Description

6.1 Overview

the TPS7A20U is designed to meet the needs of sensitive RF and analog circuits. This device provides low noise, high PSRR, low quiescent current, and low line and load transient response figures. Using innovative design techniques, the TPS7A20U offers class-leading noise performance without the need for a separate noise filter capacitor.

The TPS7A20U is designed to operate with a single $1\mu F$ input capacitor and a single $1\mu F$ ceramic output capacitor.

6.2 Functional Block Diagram



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6.3 Feature Description

6.3.1 Low Output Noise

Any internal noise at the TPS7A20U reference voltage is reduced by a first-order, low-pass RC filter before being passed to the output buffer stage. The low-pass RC filter has a –3dB cut-off frequency of approximately 0.1Hz.

During start-up, the filter resistor is bypassed to reduce output rise time. The filter begins normal operation after the output voltage reaches the correct value.

6.3.2 Smart Enable

The enable (EN) input polarity is active high. The output voltage is enabled when the enable input voltage is greater than $V_{EN(HI)}$ and disabled when the enable input voltage is less than $V_{EN(LOW)}$. If independent control of the output voltage is not needed, connect EN to IN.

This device has a smart enable circuit to reduce quiescent current. When the enable pin voltage is driven above $V_{EN(HI)}$, the device is enabled and the smart enable internal pulldown resistor ($R_{EN(PULLDOWN)}$) is disconnected. See the *Electrical Characteristics* table. When the enable pin is floating, the $R_{EN(PULLDOWN)}$ is connected and pulls the enable pin low to disable the device. The $R_{EN(PULLDOWN)}$ value is listed in the *Electrical Characteristics* table

6.3.3 Dropout Voltage

Dropout voltage (V_{DO}) is defined as $V_{IN}-V_{OUT}$ at the rated output current (I_{RATED}) , where the pass transistor is fully on. V_{IN} is the input voltage, V_{OUT} is the output voltage, and I_{RATED} is the maximum I_{OUT} listed in the *Recommended Operating Conditions* table. At this operating point, the pass transistor is driven fully on. Dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage where the output voltage is expected to stay in regulation. If the input voltage falls to less than the nominal output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source, on-state resistance ($R_{DS(ON)}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. The following equation calculates the $R_{DS(ON)}$ of the device.

$$R_{DS(ON)} = \frac{V_{DO}}{I_{RATED}}$$
 (1)

6.3.4 Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in current limit, the pass transistor dissipates power $[(VIN - VOUT) \times ICL]$. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on.

If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the Know Your Limits application note.

6.3.5 Undervoltage Lockout (UVLO)

The device has an independent undervoltage lockout (UVLO) circuit that monitors the input voltage. This circuit allows for a controlled and consistent turn on and off of the output voltage. To prevent the device from turning off if the input drops during turn on, the UVLO has hysteresis; see the *Electrical Characteristics* table.

6.3.6 Thermal Shutdown

A thermal shutdown protection circuit disables the LDO when the junction temperature (T_J) of the pass transistor rises to $T_{SD(shutdown)}$ (typical). Thermal shutdown hysteresis makes sure that the device resets (turns on) when the temperature falls to $T_{SD(reset)}$ (typical).

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The thermal time-constant of the semiconductor die is fairly short. Thus, the device cycles on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during startup is high from large $V_{\text{IN}} - V_{\text{OUT}}$ voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before startup completes.

For reliable operation, limit the junction temperature to the maximum listed in the *Recommended Operating Conditions* table. Operation above this maximum temperature causes the device to exceed operational specifications. Although the internal device protection circuitry is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

6.3.7 Active Discharge

An internal pulldown MOSFET connects a resistor from OUT to ground when the device is disabled to actively discharge the output capacitance. The active discharge circuit is activated by driving EN low or by the voltage on IN falling below the undervoltage lockout (UVLO) threshold.

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed. Reverse current potentially flows from the output to the input. This reverse current flow potentially causes damage to the device. Limit reverse current to no more than 5% of the device rated current for a short period of time.

6.4 Device Functional Modes

Table 6-1 shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

Table 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER					
OPERATING WIDDE	V _{IN}	V _{EN}	I _{OUT}	T _J		
Normal operation	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$		
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	$V_{EN} > V_{EN(HI)}$	$I_{OUT} < I_{OUT(max)}$	$T_J < T_{SD(shutdown)}$		
Disabled (any true condition disables the device)	V _{IN} < V _{UVLO}	V _{EN} < V _{EN(LOW)}	Not applicable	$T_{J} > T_{SD(shutdown)}$		

6.4.1 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage (V_{OUT(nom)} + V_{DO})
- The output current is less than the current limit (I_{OUT} < I_{CL})
- The device junction temperature is less than the thermal shutdown temperature (T_J < T_{SD})
- The enable voltage has previously exceeded the enable rising threshold voltage and has not yet decreased to less than the enable falling threshold

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. In this mode, the transient performance of the device becomes significantly degraded. During this mode, the pass transistor is driven fully on. Line or load transients in dropout potentially result in large output voltage deviations.

When the device is in a steady dropout state, the pass transistor is driven fully on. This state is defined as when the device is in dropout, directly after being in a normal regulation state, but *not* during start-up. Dropout occurs when $V_{IN} < V_{OUT(NOM)} + V_{DO}$. When the regulator exits dropout, the input voltage returns to a value $\geq V_{OUT(NOM)} + V_{DO}$. During this time, the output voltage potentially overshoots for a short period of time. $V_{OUT(NOM)}$ is the nominal output voltage and V_{DO} is the dropout voltage. During dropout exit, the device pulls the pass transistor back from being driven fully on.

6.4.3 Disabled

Shut down the output of the LDO by driving EN to less than $V_{EN(LOW)}$ (see the *Electrical Characteristics* table). When disabled, the pass transistor is turned off and internal circuits are shut down. The output voltage is also actively discharged to ground by an internal discharge circuit between OUT and ground.

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7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but use good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature. Whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors provided in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

7.1.2 Input and Output Capacitor Requirements

Although the LDO is stable without an input capacitor, good analog design practice is to connect a capacitor from IN to GND. Use a capacitor with a value at least equal to the nominal value specified in the *Recommended Operating Conditions* table. The input capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. Use this capacitor if the source impedance is greater than 0.5Ω . When the source resistance and inductance are sufficiently high, especially in the presence of load transients, the overall system is susceptible to instability. Instability includes ringing, sustained oscillation, and other performance degradation if there is insufficient capacitance between IN and GND. Use a capacitor with a value greater than the minimum if large, fast-rise-time load or line transients are anticipated. Also use a similar capacitor if the device is located more than a few centimeters from the input power source.

An output capacitor of an appropriate value helps provide stability and improve dynamic performance. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table.

7.1.3 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. There are two key transitions during a load transient response: from a light to a heavy load and from a heavy to a light load. The regions shown in Figure 7-1 are broken down as follows. Regions A, E, and H are where the output voltage is in steady-state.

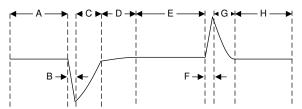


Figure 7-1. Load Transient Waveform

During transitions from a light load to a heavy load, the:

• Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B)

• Recovery from the dip results from the LDO increasing sourcing current, and leads to output voltage regulation (region C)

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to an increased output capacitor charge (region F)
- Recovery from the rise results from the LDO decreasing sourcing current in combination with the load discharging the output capacitor (region G)

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger DC load also reduces the peaks. The amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor.

7.1.4 Undervoltage Lockout (UVLO) Operation

The UVLO circuit makes sure that the device stays disabled before the input supply reaches the minimum operational voltage range. This circuit also makes sure that the device shuts down when the input supply collapses. Figure 7-2 shows the UVLO circuit response to various input voltage events. The diagram is separated into the following parts:

- Region A: The device does not start until the input reaches the UVLO rising threshold.
- · Region B: Normal operation, regulating device.
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold UVLO hysteresis). The output potentially falls out of regulation but the device remains enabled.
- · Region D: Normal operation, regulating device.
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases and the
 output falls because of the load and active discharge circuit. The device is re-enabled when the UVLO rising
 threshold is reached by the input voltage and a normal start-up follows.
- Region F: Normal operation followed by the input falling to the UVLO falling threshold.
- Region G: The device is disabled when the input voltage falls below the UVLO falling threshold to 0V. The output falls because of the load and active discharge circuit.

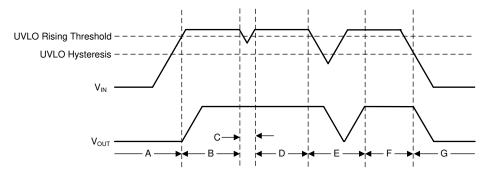


Figure 7-2. Typical UVLO Operation

7.1.5 Power Dissipation (PD)

Circuit reliability demands that proper consideration be given to device power dissipation, circuit location on the PCB, and correct thermal plane sizing. Make sure the printed circuit board (PCB) area around the regulator is as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Use Equation 2 to approximate P_D :

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
 (2)

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Power dissipation is minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A20U allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device is through the thermal pad on the package. As such, solder the thermal pad to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. According to Equation 3, power dissipation and junction temperature are most often related by the Reja of the combined PCB and device package and the TA. Reja is the junction-to-ambient thermal resistance and TA is the temperature of the ambient air. Equation 4 rearranges Equation 3 for output current.

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D}) \tag{3}$$

$$I_{OUT} = (T_J - T_A) / [R_{\theta JA} \times (V_{IN} - V_{OUT})]$$

$$\tag{4}$$

Unfortunately, this thermal resistance ($R_{\theta,JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design. Therefore, this resistance varies according to the total copper area, copper weight, and location of the planes. The R_{θJA} recorded in the *Thermal Information* table is determined by the JEDEC standard, PCB, and copper-spreading area. R_{0JA} is only used as a relative measure of package thermal performance. For a well-designed thermal layout, R_{θJA} is actually the sum of the DSBGA R_{θJC(bot)} plus the thermal resistance contribution by the PCB copper $R_{\theta,JC(bot)}$ is the package junction-to-case (bottom) thermal resistance.

7.1.5.1 Estimating Junction Temperature

The JEDEC standard now recommends using psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics (Ψ_{.IT} and $\Psi_{\rm JB}$) are used in accordance with Equation 5 and are given in the *Thermal Information* table.

$$\Psi_{JT}: T_J = T_T + \Psi_{JT} \times P_D \text{ and } \Psi_{JB}: T_J = T_B + \Psi_{JB} \times P_D$$
(5)

where:

- P_D is the power dissipated as explained in Equation 2
- T_T is the temperature at the center-top of the device package
- T_B is the PCB surface temperature measured 1mm from the device package and centered on the package edge

7.1.5.2 Recommended Area for Continuous Operation

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator is given in Figure 7-3 and is separated into the following parts:

- Dropout voltage limits the minimum differential voltage between the input and the output $(V_{IN} V_{OUT})$ at a given output current level. See the *Dropout Operation* section for more details.
- The rated output current limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- The rated junction temperature limits the maximum junction temperature of the device. Exceeding this rating causes the device to fall out of specification and reduces long-term reliability.
 - The shape of the slope is given by Equation 4. The slope is nonlinear because the maximum-rated junction temperature of the LDO is controlled by the power dissipation across the LDO. Thus, when $V_{\rm IN}$ – V_{OUT} increases the output current decreases.
- The rated input voltage range governs both the minimum and maximum of $V_{IN} V_{OUT}$.

Figure 7-3 shows the recommended area of operation for this device on a JEDEC-standard high-K board with a $R_{\theta,JA}$, as given in the *Thermal Information* table.

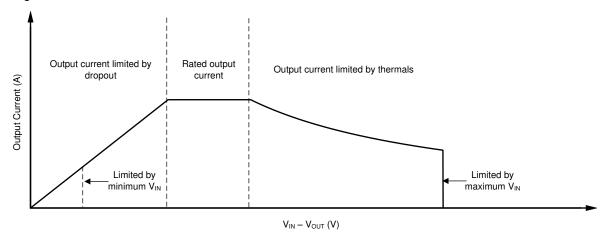


Figure 7-3. Region Description of Continuous Operation Regime

7.2 Typical Application

Figure 7-4 shows the typical application circuit for the TPS7A20. If needed, increase the input and output capacitances above the 1μ F minimum for some applications.

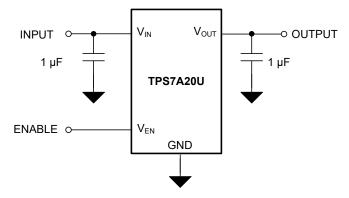


Figure 7-4. TPS7A20U Typical Application

7.2.1 Design Requirements

Table 7-1 summarizes the design requirements for Figure 7-4.

Table 7-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	4.5V to 5.5V
Output voltage	4.1V
Output current	70mA
Maximum ambient temperature	85°C

7.2.2 Detailed Design Procedure

For this design example, the 4.1V output version (TPS7A20U41) is selected. A nominal 5V input supply is assumed. Use a minimum $1.0\mu F$ input capacitor to minimize the effect of resistance and inductance between the 5V source and the LDO input. Also use a minimum $1.0\mu F$ output capacitor for stability and good load transient response. The dropout voltage (V_{DO}) is less than 95mV maximum at a 4.1V output voltage and 75mA output current. Thus, there are no dropout issues with a minimum 4.5V input voltage and a maximum 75mA output current.

7.2.3 Application Curve

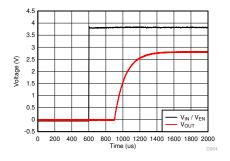


Figure 7-5. Start-Up

7.3 Power Supply Recommendations

This device is designed to operate from an input supply voltage range of 1.6V to 6.0V. Make sure the input supply is well regulated and free of spurious noise. Set the input supply to be at least $V_{OUT(nom)} + 0.3V$ or 1.6V, whichever is greater. This setting makes sure that the output voltage is well regulated and dynamic performance is optimum. Use a $1\mu F$ or greater input capacitor to reduce the impedance of the input supply, especially during transients.

7.4 Layout

7.4.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible.
- Use copper planes for device connections to optimize thermal performance.
- Place thermal vias around the device to distribute the heat.
- Do not place a thermal via directly beneath the thermal pad of the YCK package. A via wicks solder or solder paste away from the thermal pad joint during the soldering process, thus leading to a compromised solder joint on the thermal pad.



7.4.2 Layout Example

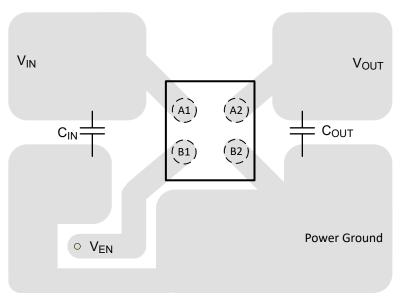


Figure 7-6. YCK Package (DSBGA) Typical Layout



8 Device and Documentation Support

8.1 Device Support

8.1.1 Device Nomenclature

Table 8-1. Device Nomenclature

PRODUCT (1) (2)	V _{OUT}						
TPS7A20Uxx(x)Pyyyz	 xx(x) is the nominal output voltage. For output voltages with a resolution of 100mV, two digits are used in the ordering number. Otherwise, three digits are used (for example, 28 = 2.8V; 125 = 1.25V). P indicates an active output discharge feature. yyy is the package designator. z is the package quantity. R is for reel (12000 pieces for YCK). 						

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.
- (2) Output voltages from 0.8V to 5.5V in 25mV increments are available. Contact the factory for details and availability.

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (August 2024) to Revision A (September 2024)

Page

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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8-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
TPS7A20U18PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	V
TPS7A20U18PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	V
TPS7A20U25PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Т
TPS7A20U25PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Т
TPS7A20U30PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	W
TPS7A20U30PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	W
TPS7A20U31PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Υ
TPS7A20U31PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Υ
TPS7A20U33PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Z
TPS7A20U33PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	Z
TPS7A20U41PYCKR	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	U
TPS7A20U41PYCKR.A	Active	Production	DSBGA (YCK) 4	12000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 125	U

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A20U18PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U18PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U25PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U25PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U30PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U30PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U31PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U31PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U33PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U33PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U41PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1
TPS7A20U41PYCKR	DSBGA	YCK	4	12000	180.0	8.4	0.71	0.71	0.42	2.0	8.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A20U18PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U18PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U25PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U25PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U30PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U30PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U31PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U31PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U33PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U33PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U41PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0
TPS7A20U41PYCKR	DSBGA	YCK	4	12000	182.0	182.0	20.0

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